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Dade

Patent  
Attorney's Docket No. 004501-616

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of

THOMAS LANG

Application No.: Unassigned

Filed: November 20, 2001

For: HIGH-POWER SEMICONDUCTOR  
MODULE, AND USE OF SUCH A  
HIGH-POWER SEMICONDUCTOR  
MODULE

)  
)  
) Group Art Unit: Unassigned

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) Examiner: Unassigned  
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10996 U.S. PTO  
09/988740  
11/20/01

INFORMATION DISCLOSURE STATEMENT  
TRANSMITTAL LETTER

Assistant Commissioner for Patents  
Washington, D.C. 20231

Sir:

Enclosed is an Information Disclosure Statement and accompanying form PTO-1449 for the above-identified patent application.

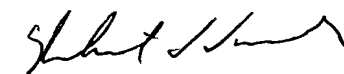
- ☒ No additional fee for submission of an IDS is required.
- ☐ The fee of \$180.00 (126) as set forth in 37 C.F.R. § 1.17(p) is also enclosed.
- ☐ A certification under 37 C.F.R. § 1.97(e) is also enclosed.
- ☐ A certification under 37 C.F.R. § 1.97(e), and the fee of \$180.00 (126) as set forth in 37 C.F.R. § 1.17(p) are also enclosed.
- ☐ Charge \$\_\_\_\_\_ to Deposit Account No. 02-4800 for the fee due.
- ☐ A check in the amount of \$\_\_\_\_\_ is enclosed for the fee due.

The Commissioner is hereby authorized to charge any appropriate fees under 37 C.F.R. §§ 1.16, 1.17 and 1.21 that may be required by this paper, and to credit any overpayment, to Deposit Account No. 02-4800. This paper is submitted in duplicate.

Respectfully submitted,

BURNS, DOANE, SWECKER & MATHIS, L.L.P.

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jc996 U.S. PTO  
09/988540



**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re application of

Thomas LANG

(inventors)

claiming Priority under 35 U.S.C. 119

of application No.: 00811110.6

in: EUROPE

with filing date of: November 22, 2000

U.S. Serial Number:

U.S. filing date:

Title: HIGH POWER SEMICONDUCTOR MODULE, AND USE OF SUCH A HIGH-  
POWER SEMICONDUCTOR MODULE

**INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR 1.97**

Honorable Commissioner of Patents and Trademarks, Washington, D.C. 20231

Sir:

Submitted herewith is a Search Report/Examination Report issued in a corresponding foreign patent application by the

European Patent Office (X)

German Patent Office ()

()

1. We wish to make of record the certain citations listed in the Search Report/Examination Report in accordance with 37 CFR 1.97.

2. The relevance of each listed item with regard to the different claims of the above-identified application according to the opinion of the Search Authority/Examination Authority, is indicated in the Search Report/Examination Report

by reference to certain categories which are explained on the Report sheet or in MPEP on page 1800 - 55, resp. (x)

3. The claims as filed in the above-identified U.S. patent application

correspond to ☒ (x)

are different from ☐ ( )

the claims for which the Search Report/Examination Report has been established.

4. Copies of the references cited are enclosed herewith.

All citations ☒ (x)

All relevant citations except U.S. patents ☐ ( )

5. English translations of pertinent portions of any non-English references are enclosed herewith, if such translation is readily available.


6. No copies are enclosed herewith of references which are characterized by an "A" in the Search Report/Examination Report, since "A" indicates that such reference is not relevant for the invention. ☐ ( )

Additionally, copies of the references cited in the specification are enclosed. ☒ (X )

Respectfully submitted,

Date: 12<sup>th</sup> September 2001

by:



Gilbert Zimmermann